

Supporting Information

In situ Generated Polysiloxanes Stabilizing μ_3 -Oxo Bridged Sb_3 Triangles

M. Santhana Raj Prabhu,^a Uppara Ugandhar^a and Viswanathan Baskar^{*a}

^aSchool of Chemistry, University of Hyderabad, Hyderabad 500046, Telengana, India.

E-mail: vbasc@uohyd.ernet.

Contents

1. **Figure. S1.** ORTEP view of molecular structure **1** with thermal ellipsoids shown at 30% probability.
3. **Figure. S2.** ORTEP view of molecular structure **2** with thermal ellipsoids shown at 30% probability.
4. **Figure. S3.** ORTEP view of molecular structure **3** with thermal ellipsoids shown at 30% probability.
5. **Figure. S4.** ORTEP view of molecular structure **4** with thermal ellipsoids shown at 30% probability.
6. **Figure. S5.** ESI-MS of compound **1** in positive ion mode.
7. **Figure. S6.** ESI-MS of compound **2** in positive ion mode.
8. **Figure. S7.** ESI-MS of compound **3** in positive ion mode.
9. **Figure. S8.** ESI-MS of compound **4** in positive ion mode.
10. **Table S1.** Crystal data and structure refinement details for compounds **1-4**.
11. **Table S2.** Selected bond lengths (Å) and bond angles (°) parameters for compounds **1**.
12. **Table S3.** Selected bond lengths (Å) and bond angles (°) parameters for compounds **2**.
13. **Table S4.** Selected bond lengths (Å) and bond angles (°) parameters for compounds **3**.
14. **Table S5.** Selected bond lengths (Å) and bond angles (°) parameters for compounds **4**.

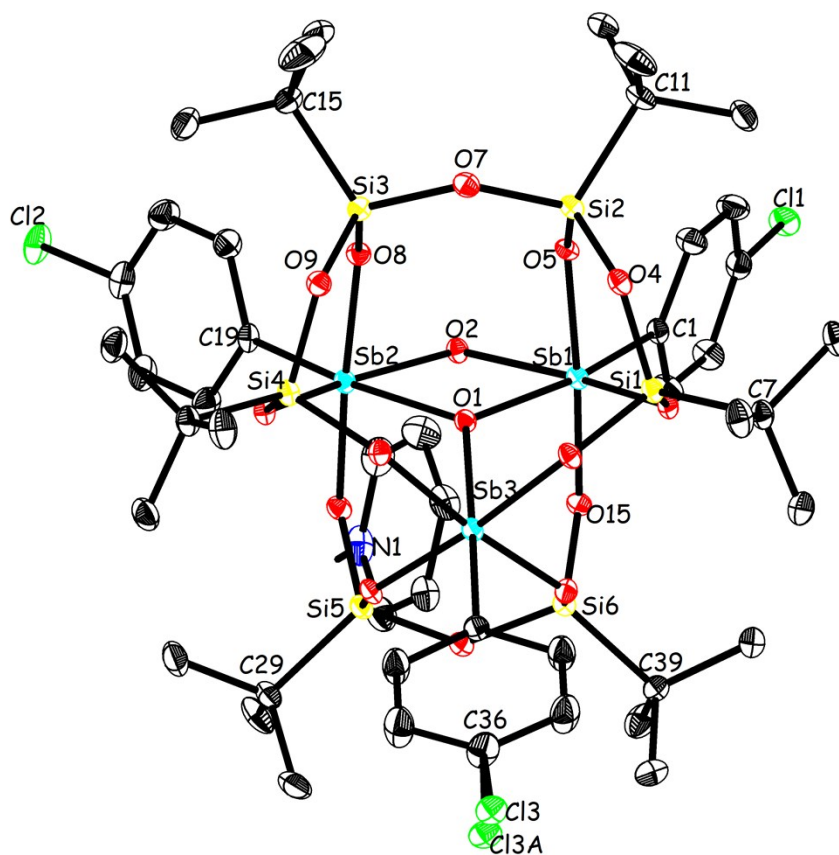


Figure. S1 ORTEP view of molecular structure **1** with thermal ellipsoids shown at 30% probability and hydrogen atoms are omitted for clarity.

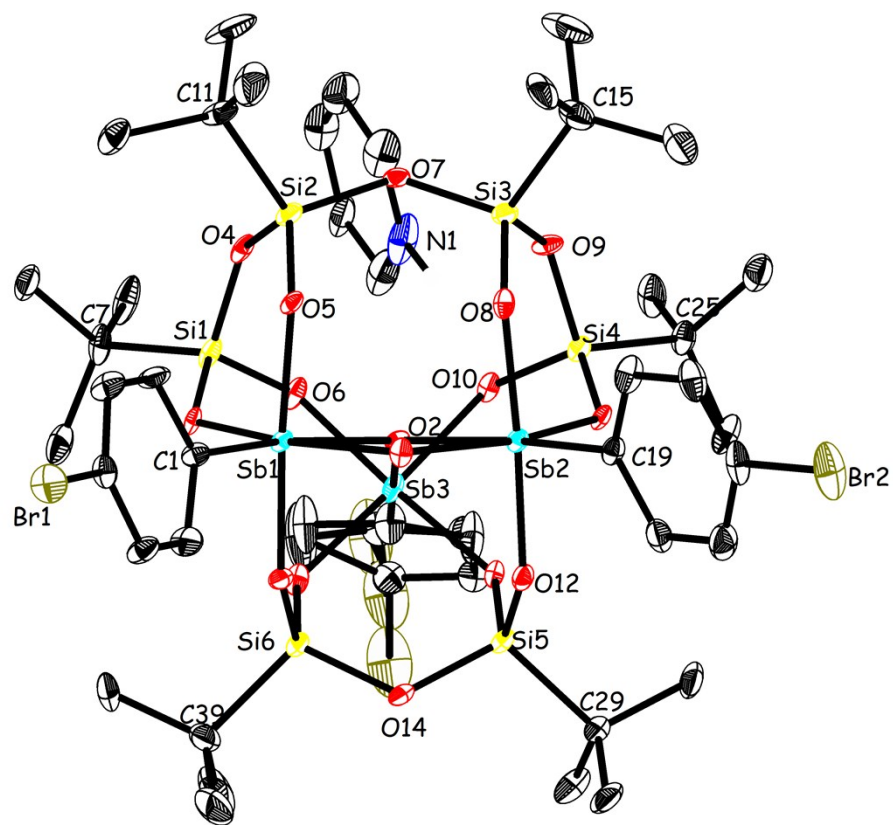


Figure. S2 ORTEP view of molecular structure **2** with thermal ellipsoids shown at 30% probability and hydrogen atoms are omitted for clarity.

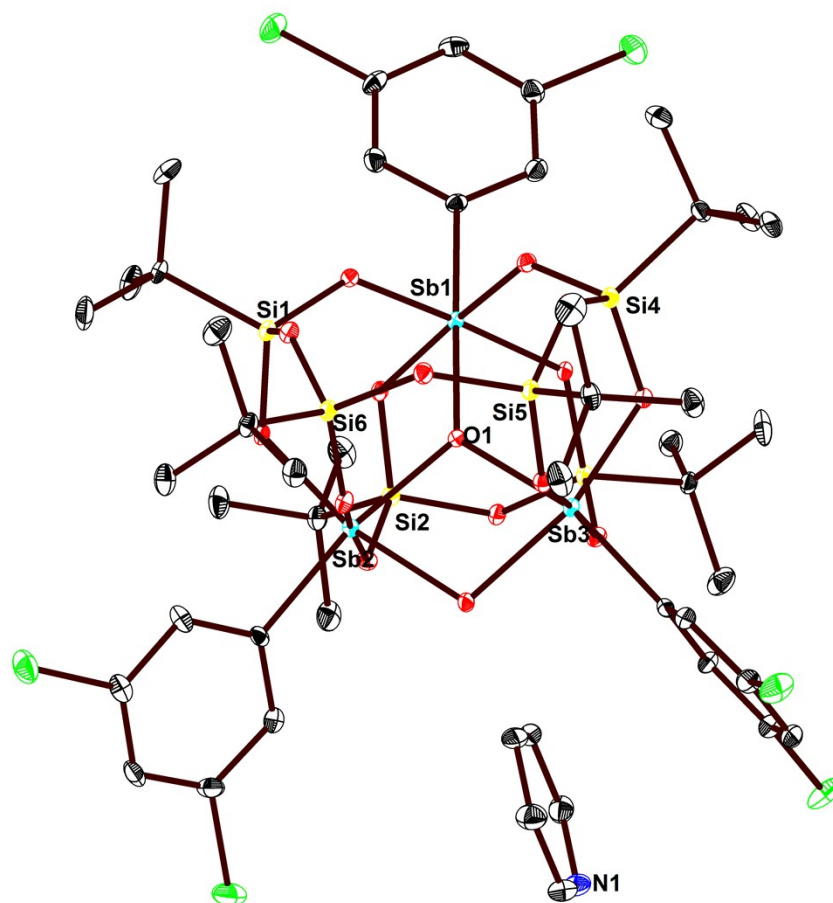


Figure. S3 ORTEP view of molecular structure **3** with thermal ellipsoids shown at 30% probability and hydrogen atoms are omitted for clarity.

BRUKER MAXIS HRMS REPORT

School of Chemistry
University of Hyderabad

Analysis Info

Analysis Name D:\Data\2014\Dr.V.BHASKER\JUNE\SRP-796A.d
Method tune_wide_Pos.m
Sample Name SRP-796A-CHCL3-ACN
Comment

Acquisition Date 6/11/2014 4:22:03 PM

Operator Ramu Sridhar
Instrument maXis 10138

Acquisition Parameter

Source Type	ESI	Ion Polarity	Positive	Set Nebulizer	4.4 psi
Focus	Not active	Set Capillary	3800 V	Set Dry Heater	180 °C
Scan Begin	280 m/z	Set End Plate Offset	-500 V	Set Dry Gas	4.0 l/min
Scan End	2900 m/z	Set Collision Cell RF	2500.0 Vpp	Set Divert Valve	Source

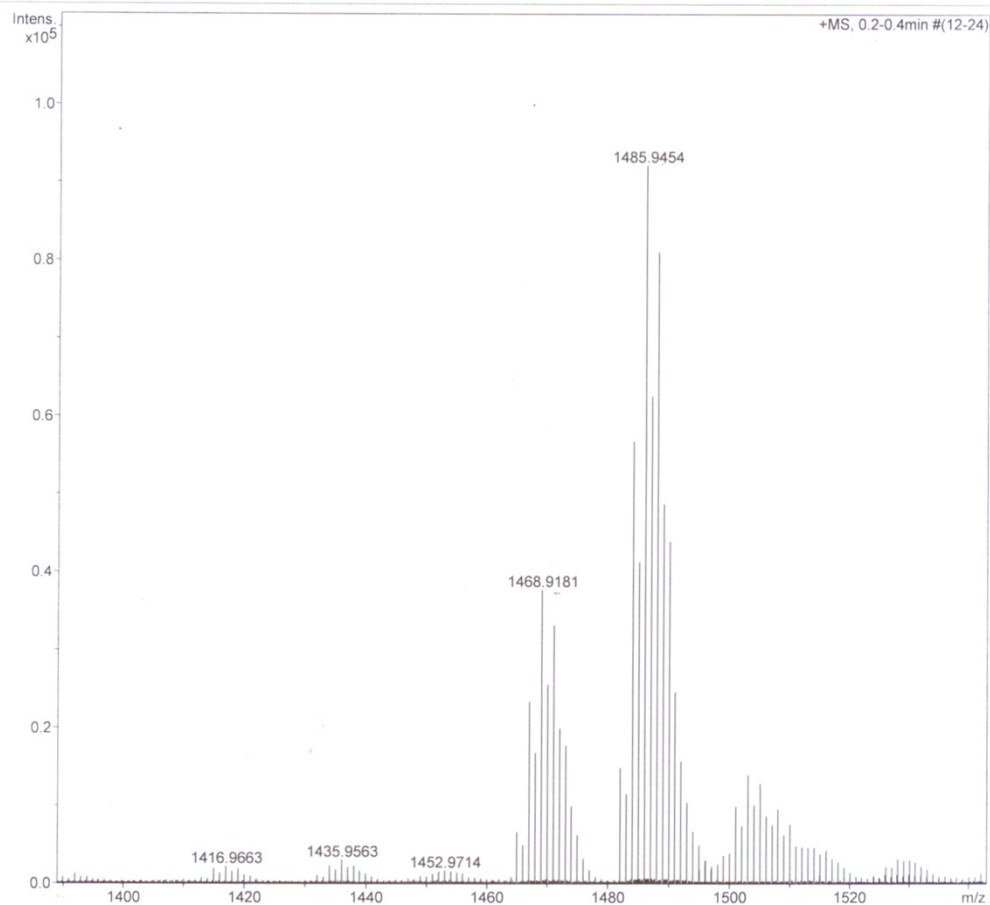


Figure. S5 ESI-MS of compound **1** in positive ion mode.

HRMS (ESI) calcd for (C₄₂H₆₇Cl₃O₁₆Sb₃Si₆) [M+2H]⁺ 1468.9356; found 1468.9181

BRUKER MAXIS HRMS REPORT

School of Chemistry
University of Hyderabad

Analysis Info

Analysis Name D:\Data\2013\DR.V BHASKER\NOV\SRP-174CRY.d
Method tune_wide_Pos.m
Sample Name SRP-174CRY-DCM-MEOH
Comment

Acquisition Date 11/22/2013 1:10:47 PM

Operator Ramu Sridhar
Instrument maXis 10138

Acquisition Parameter

Source Type	ESI	Ion Polarity	Positive	Set Nebulizer	4.4 psi
Focus	Not active	Set Capillary	3800 V	Set Dry Heater	180 °C
Scan Begin	280 m/z	Set End Plate Offset	-500 V	Set Dry Gas	4.0 l/min
Scan End	2900 m/z	Set Collision Cell RF	2500.0 Vpp	Set Divert Valve	Source

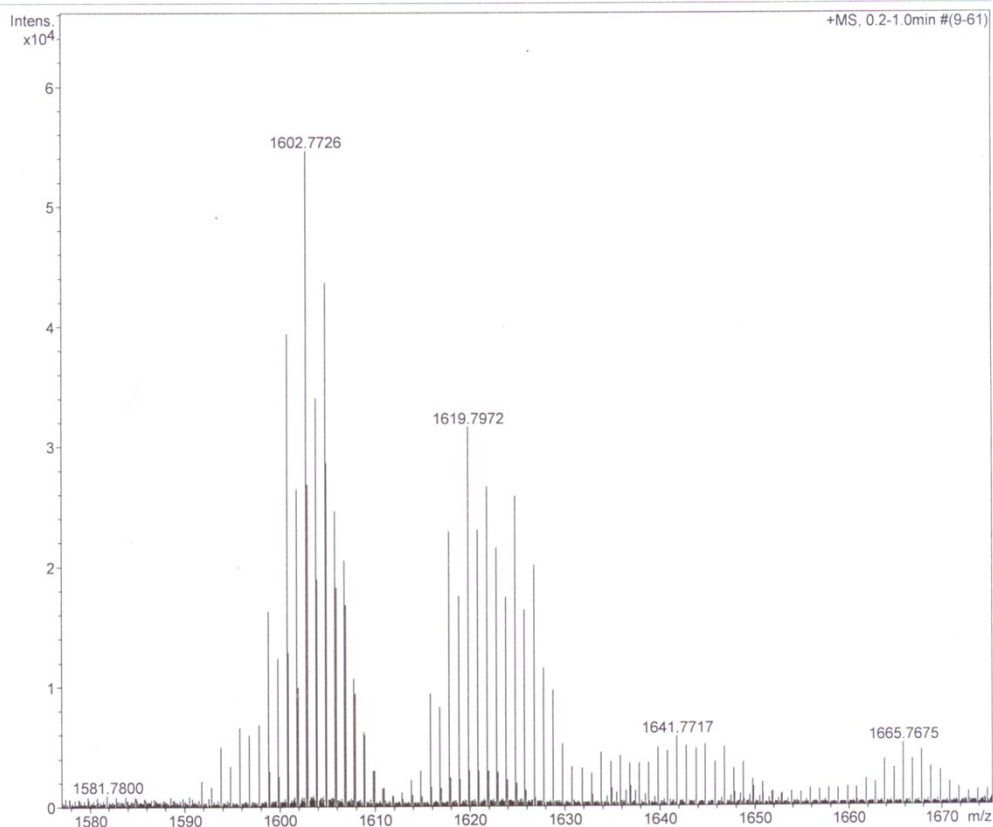


Figure. S6 ESI-MS of compound **2** in positive ion mode.

HRMS (ESI) calcd for (C₄₂H₆₇Br₃O₁₆Sb₃Si₆) [M+2H]⁺ 1602.7829; found 1602.7726

BRUKER MAXIS HRMS REPORT

School of Chemistry
University of Hyderabad

Analysis Info

Analysis Name D:\Data\2015\PROF.VB\FEB\SRP-184CRY.d
Method tune_wide_Pos.m
Sample Name SRP-184CRY-CHCL3-ACN
Comment

Acquisition Date 2/24/2015 1:04:58 PM

Operator Ramu Sridhar
Instrument maXis 10138

Acquisition Parameter

Source Type	ESI	Ion Polarity	Positive	Set Nebulizer	0.3 Bar
Focus	Not active	Set Capillary	3800 V	Set Dry Heater	180 °C
Scan Begin	280 m/z	Set End Plate Offset	-500 V	Set Dry Gas	4.0 l/min
Scan End	2900 m/z	Set Collision Cell RF	2500.0 Vpp	Set Divert Valve	Source

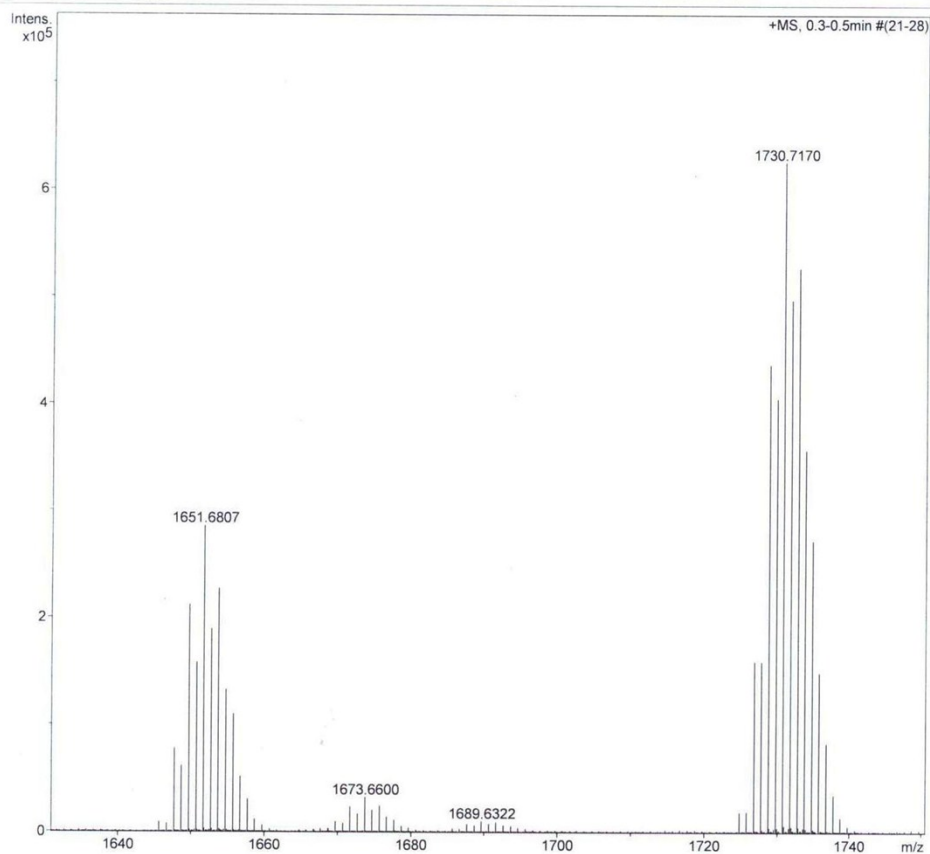


Figure S7. ESI-MS of compound **3** in positive ion mode.

HRMS (ESI) calcd for (C₄₂H₆₃Cl₆O₁₆Sb₃Si₆) [M+2K+3H]⁺ 1651.0119; found 1651.6807

BRUKER MAXIS HRMS REPORT

School of Chemistry
University of Hyderabad

Analysis Info

Analysis Name D:\Data\2015\PROF.KCK\FEB\UGANTHAR R.d
Method tune_low.m
Sample Name UGANTHAR R
Comment

Acquisition Date 2/12/2015 4:42:06 PM

Operator Ramu Sridhar
Instrument maXis 10138

Acquisition Parameter

Source Type	ESI	Ion Polarity	Positive	Set Nebulizer	4.4 psi
Focus	Not active	Set Capillary	4500 V	Set Dry Heater	200 °C
Scan Begin	50 m/z	Set End Plate Offset	-500 V	Set Dry Gas	4.0 l/min
Scan End	1800 m/z	Set Collision Cell RF	350.0 Vpp	Set Divert Valve	Waste

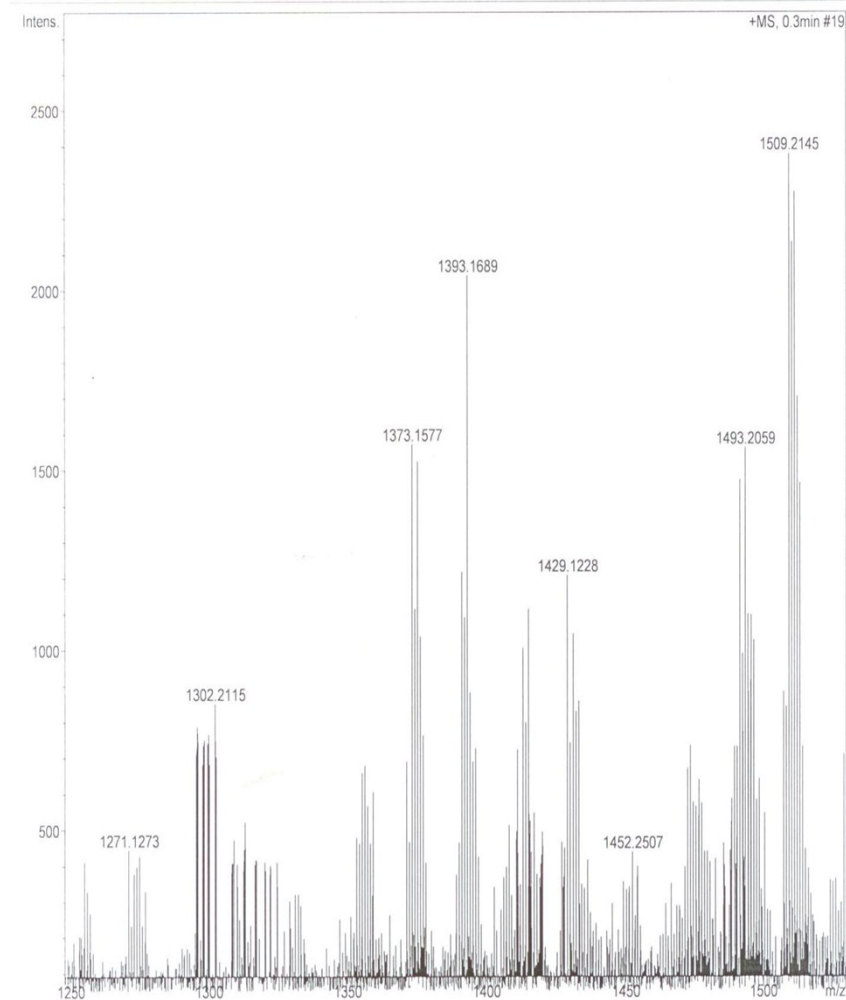


Figure S8. ESI-MS of compound **4** in positive ion mode.

HRMS (ESI) calcd for (C₅₁H₈₉O₁₇Sb₃Si₆) [M+H]⁺ 1509.1917; found 1509.2145.

Table S1: Crystal data and structure refinement details for compounds 1-4.

	1	2	3	4
formula	C ₅₀ H ₈₁ Cl ₃ O ₁₇ NSb ₃ Si ₆	C ₅₀ H ₈₁ Br _{2.99} O ₁₇ NSb ₃ Si ₆	C ₅₁ H ₇₅ Cl ₆ N ₃ O ₁₆ Sb ₃ Si ₆	C ₆₁ H ₁₀₆ N ₅ O ₁₇ Si ₆ Sb ₃
M	1608.29	1740.87	1732.63	1715.29
T(K)	100(2)	100(2)	100(2)	100(2)
λ (Å)	0.71073	0.71073	0.71073	0.71073
crystal system	Monoclinic	Monoclinic	Triclinic	Triclinic
space group	<i>P2(1)/n</i>	<i>P2(1)/c</i>	<i>P</i> -1	<i>P</i> -1
a(Å)	11.7571(10)	11.741 (10)	12.3465(14)	15.0752(12)
b(Å)	28.053(2)	28.21 (2)	13.1911(15)	16.0739(13)
c(Å)	21.7258 (19)	21.863 (18)	23.155(3)	16.9080(14)
α (deg)	90	90	99.920(2)	100.488(10)
β (deg)	104.9530 (10)	104.994 (14)	95.997(2)	91.038(10)
γ (deg)	90	90	105.084(2)	91.518(10)
V(Å ³)	6923.0 (10)	6993 (10)	3542.3(7)	4026.1(6)
Z	4	4	2	2
D _{calcd} (Mg m ⁻³)	1.543	1.653	1.624	1.415
μ (mm ⁻¹)	1.442	3.021	1.524	1.149
F(000)	3248	3463	1738	1760
θ range (deg)	1.212-25.088	1.205-25.026	1.634 to 26.441	1.225 to 25.038
index range	-14 $\leq$ h $\leq$ 14	-13 $\leq$ h $\leq$ 13	-15 $\leq$ h $\leq$ 15	-17 $\leq$ h $\leq$ 17
	-33 $\leq$ k $\leq$ 33	-33 $\leq$ k $\leq$ 33	-16 $\leq$ k $\leq$ 16	-19 $\leq$ k $\leq$ 19
	-25 $\leq$ l $\leq$ 25	-25 $\leq$ l $\leq$ 25	-26 $\leq$ l $\leq$ 28	-20 $\leq$ l $\leq$ 20
reflections collected	66491	66654	28581	38923
goodness-of-fit (GOF) on F ²	1.042	1.104	1.026	1.041
final R indices	$R_1 = 0.0311$	$R_1 = 0.0694$	$R_1 = 0.0413$	$R_1 = 0.0279$
$R_1[I > 2\sigma(I)]$	$wR_2 = 0.0776$	$wR_2 = 0.1310$	$wR_2 = 0.0943$	$wR_2 = 0.0704$
R indices (all data)	$R_1 = 0.0347$	$R_1 = 0.0957$	$R_1 = 0.0505$	$R_1 = 0.0313$
	$wR_2 = 0.0796$	$wR_2 = 0.1414$	$wR_2 = 0.0991$	$wR_2 = 0.0725$
large diff. peak and hole (e Å ⁻³)	1.645 and -0.920	1.557 and -1.348	1.982 and -0.811	0.886 and -1.004

Table S2: Selected bond lengths (Å) and bond angles (°) parameters for compound 1

Sb(1)-C(1)	2.121(3)	Si(4)-O(10)	1.637(2)
Sb(2)-C(19)	2.117(3)	Si(4)-O(9)	1.644(2)
Sb(3)-C(33)	2.112(3)	Si(5)-O(13)	1.626(2)
Sb(1)-O(3)	1.939(2)	Si(5)-O(12)	1.629(2)
Sb(1)-O(15)	1.960(2)	Si(5)-O(14)	1.645(2)
Sb(1)-O(5)	1.988(2)	Si(6)-O(16)	1.620(2)
Sb(1)-O(2)	2.087(2)	Si(6)-O(15)	1.628(2)
Sb(1)-O(1)	2.094(2)	Si(6)-O(14)	1.646(2)
Sb(2)-O(11)	1.946(2)	Sb(1)-O(1)-Sb(2)	105.31(9)
Sb(2)-O(12)	1.953(2)	Sb(1)-O(1)-Sb(3)	124.84(10)
Sb(2)-O(8)	1.978(2)	Sb(2)-O(1)-Sb(3)	125.58(10)
Sb(2)-O(2)	2.082(2)	Sb(2)-O(2)-Sb(1)	106.61(11)
Sb(2)-O(1)	2.110(2)	Si(4)-O(11)-Sb(2)	125.82(13)
Sb(3)-O(16)	1.951(2)	Si(1)-O(3)-Sb(1)	125.31(13)
Sb(3)-O(13)	1.953(2)	Si(6)-O(15)-Sb(1)	130.55(13)
Sb(3)-O(6)	1.953(2)	Si(4)-O(10)-Sb(3)	133.43(13)
Sb(3)-O(10)	1.983(2)	Si(5)-O(12)-Sb(2)	130.12(13)
Sb(3)-O(1)	2.176(2)	Si(6)-O(16)-Sb(3)	127.23(13)
Si(1)-O(6)	1.621(2)	Si(2)-O(4)-Si(1)	130.88(15)
Si(1)-O(3)	1.635(2)	Si(2)-O(5)-Sb(1)	132.56(13)
Si(1)-O(4)	1.639(2)	Si(1)-O(6)-Sb(3)	133.36(13)
Si(2)-O(5)	1.626(2)	Si(5)-O(14)-Si(6)	124.78(14)
Si(2)-O(4)	1.631(2)	Si(5)-O(13)-Sb(3)	127.28(13)
Si(2)-O(7)	1.637(2)	Si(3)-O(7)-Si(2)	138.01(15)
Si(3)-O(8)	1.618(2)	Si(3)-O(8)-Sb(2)	134.17(13)
Si(3)-O(7)	1.633(2)	Si(3)-O(9)-Si(4)	129.84(15)
Si(3)-O(9)	1.639(2)		
Si(4)-O(11)	1.626(2)		

Table S3: Selected bond lengths (Å) and bond angles (°) parameters for compound 2

Sb(1)-C(1)	2.123(8)	Si(4)-O(11)	1.612(6)
Sb(2)-C(19)	2.121(8)	Si(4)-O(9)	1.632(6)
Sb(3)-C(33B)	2.098(13)	Si(4)-O(10)	1.640(6)
Sb(3)-C(33A)	2.118(13)	Si(5)-O(12)	1.616(6)
Sb(1)-O(3)	1.926(5)	Si(5)-O(13)	1.625(6)
Sb(1)-O(15)	1.960(5)	Si(5)-O(14)	1.640(6)
Sb(1)-O(5)	1.979(5)	Si(6)-O(16)	1.612(6)
Sb(1)-O(1)	2.083(5)	Si(6)-O(15)	1.617(6)
Sb(1)-O(2)	2.0852(13)	Si(6)-O(14)	1.635(6)
Sb(2)-O(11)	1.943(5)	Sb(2)-O(2)-Sb(1)	106.17(5)
Sb(2)-O(12)	1.950(5)	Sb(1)-O(1)-Sb(2)	105.5(2)
Sb(2)-O(8)	1.959(5)	Sb(1)-O(1)-Sb(3)	124.7(2)
Sb(2)-O(2)	2.0844(13)	Sb(2)-O(1)-Sb(3)	125.7(2)
Sb(2)-O(1)	2.106(5)	Si(3)-O(8)-Sb(2)	134.2(3)
Sb(3)-O(13)	1.933(5)	Si(1)-O(3)-Sb(1)	125.3(3)
Sb(3)-O(6)	1.943(5)	Si(6)-O(15)-Sb(1)	130.5(3)
Sb(3)-O(16)	1.953(6)	Si(2)-O(5)-Sb(1)	132.2(3)
Sb(3)-O(10)	1.988(5)	Si(1)-O(6)-Sb(3)	133.9(3)
Sb(3)-O(1)	2.169(5)	Si(3)-O(9)-Si(4)	130.0(3)
Si(1)-O(6)	1.609(6)	Si(5)-O(12)-Sb(2)	130.0(3)
Si(1)-O(4)	1.634(6)	Si(5)-O(13)-Sb(3)	127.4(3)
Si(1)-O(3)	1.641(6)	Si(4)-O(10)-Sb(3)	133.0(3)
Si(2)-O(7)	1.628(6)	Si(4)-O(11)-Sb(2)	125.8(3)
Si(2)-O(4)	1.630(6)	Si(2)-O(4)-Si(1)	131.5(3)
Si(2)-O(5)	1.633(6)	Si(2)-O(7)-Si(3)	138.2(3)
Si(3)-O(8)	1.618(6)	Si(6)-O(16)-Sb(3)	126.9(3)
Si(3)-O(9)	1.631(6)	Si(6)-O(14)-Si(5)	124.6(4)
Si(3)-O(7)	1.635(6)		

Table S4: Selected bond lengths (Å) and bond angles (°) parameters for compound 3

Sb(1)-C(1)	2.117(4)	Si(4)-O(10)	1.629(3)
Sb(2)-C(19)	2.135(4)	Si(4)-O(11)	1.629(3)
Sb(3)-C(33)	2.122(4)	Si(4)-O(9)	1.641(3)
Sb(1)-O(3)	1.940(3)	Si(5)-O(13)	1.629(3)
Sb(1)-O(15)	1.961(3)	Si(5)-O(12)	1.633(3)
Sb(1)-O(5)	1.983(2)	Si(5)-O(14)	1.642(3)
Sb(1)-O(1)	2.073(3)	Si(6)-O(16)	1.626(3)
Sb(1)-O(2)	2.087(3)	Si(6)-O(15)	1.632(3)
Sb(2)-O(12)	1.939(3)	Si(6)-O(14)	1.648(3)
Sb(2)-O(11)	1.950(3)	Sb(1)-O(1)-Sb(2)	105.99(11)
Sb(2)-O(8)	1.958(2)	Sb(1)-O(1)-Sb(3)	124.24(12)
Sb(2)-O(1)	2.090(3)	Sb(2)-O(1)-Sb(3)	125.60(12)
Sb(2)-O(2)	2.103(3)	Sb(1)-O(2)-Sb(2)	105.02(12)
Sb(3)-O(16)	1.946(3)	Si(5)-O(12)-Sb(2)	129.47(16)
Sb(3)-O(6)	1.958(3)	Si(6)-O(15)-Sb(1)	129.00(16)
Sb(3)-O(13)	1.959(3)	Si(1)-O(6)-Sb(3)	132.20(16)
Sb(3)-O(10)	1.964(3)	Si(2)-O(5)-Sb(1)	132.71(16)
Sb(3)-O(1)	2.196(3)	Si(3)-O(8)-Sb(2)	133.82(15)
Si(1)-O(6)	1.624(3)	Si(1)-O(3)-Sb(1)	125.68(15)
Si(1)-O(3)	1.632(3)	Si(4)-O(10)-Sb(3)	132.65(16)
Si(1)-O(4)	1.640(3)	Si(5)-O(14)-Si(6)	124.77(17)
Si(2)-O(5)	1.621(3)	Si(5)-O(13)-Sb(3)	128.12(15)
Si(2)-O(4)	1.638(3)	Si(6)-O(16)-Sb(3)	128.20(15)
Si(2)-O(7)	1.641(3)	Si(4)-O(11)-Sb(2)	125.83(15)
Si(3)-O(8)	1.623(3)	Si(2)-O(4)-Si(1)	132.68(18)
Si(3)-O(7)	1.629(3)	Si(3)-O(7)-Si(2)	137.12(18)
Si(3)-O(9)	1.636(3)	Si(3)-O(9)-Si(4)	130.53(18)

Table S5: Selected bond lengths (Å) and bond angles (°) parameters for compound 4.

Sb(1)-C(1)	2.098(3)	Si(4)-O(10)	1.6012(19)
Sb(2)-C(10)	2.095(3)	Si(4)-O(11)	1.620(2)
Sb(3)-C(19)	2.095(3)	Si(4)-O(9)	1.6423(19)
Sb(1)-O(14)	1.9625(18)	Si(5)-O(11)	1.610(2)
Sb(1)-O(10)	1.9681(17)	Si(5)-O(13)	1.615(2)
Sb(1)-O(16)	1.9715(17)	Si(5)-O(12)	1.644(2)
Sb(1)-O(8)	1.9727(17)	Si(6)-O(14)	1.6077(19)
Sb(1)-O(5)	2.0959(16)	Si(6)-O(13)	1.628(2)
Sb(2)-O(15)	1.9147(17)	Si(6)-O(6)	1.6357(18)
Sb(2)-O(6)	1.9234(17)	Sb(2)-O(2)-Sb(3)	93.20(7)
Sb(2)-O(5)	2.0793(16)	Sb(2)-O(1)-Sb(3)	92.51(7)
Sb(2)-O(2)	2.1000(19)	Sb(3)-O(5)-Sb(2)	95.57 (7)
Sb(2)-O(1)	2.1014(18)	Sb(3)-O(5)-Sb(1)	131.79(8)
Sb(3)-O(9)	1.9176(18)	Sb(2)-O(5)-Sb(1)	132.64(8)
Sb(3)-O(7)	1.9236(18)	Si(6)-O(14)-Sb(1)	141.09(11)
Sb(3)-O(5)	2.0440(16)	Si(3)-O(16)-Sb(1)	138.97(11)
Sb(3)-O(2)	2.1033(18)	Si(1)-O(8)-Sb(1)	138.61(11)
Sb(3)-O(1)	2.1259(18)	Si(3)-O(15)-Sb(2)	134.18(10)
Si(1)-O(8)	1.6062(18)	Si(1)-O(7)-Sb(3)	135.21(11)
Si(1)-O(18)	1.6299(19)	Si(2)-O(17)-Si(3)	150.60(13)
Si(1)-O(7)	1.6400(19)	Si(6)-O(6)-Sb(2)	133.29(11)
Si(2)-O(17)	1.6053(19)	Si(4)-O(10)-Sb(1)	141.54(11)
Si(2)-O(18)	1.6189(19)	Si(2)-O(18)-Si(1)	142.80(12)
Si(2)-O(19)	1.6465(19)	Si(4)-O(9)-Sb(3)	135.35(11)
Si(3)-O(16)	1.6098(18)	Si(5)-O(13)-Si(6)	145.59(13)
Si(3)-O(17)	1.6297(19)	Si(5)-O(11)-Si(4)	145.05(14)
Si(3)-O(15)	1.6384(18)		